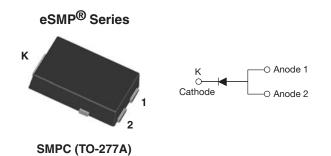
### **Vishay Semiconductors**

www.vishay.com

# Hyperfast Rectifier, 8 A FRED Pt<sup>®</sup>



### LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS          |        |  |  |  |
|----------------------------------|--------|--|--|--|
| I <sub>F(AV)</sub> 8 A           |        |  |  |  |
| V <sub>R</sub>                   | 100 V  |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 0.78 V |  |  |  |
| t <sub>rr (typ.)</sub>           | 28 ns  |  |  |  |
| T <sub>J</sub> max.              | 175 °C |  |  |  |
| Package SMPC (TO-277A)           |        |  |  |  |
| Circuit configuration            | Single |  |  |  |

### FEATURES

- Hyperfast recovery time, reduced Q<sub>rr</sub>, and soft recovery
- 175 °C maximum operating junction temperature
- Specified for output and snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in snubber, boost, lighting, as high frequency rectifiers and freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

#### **MECHANICAL DATA**

Case: SMPC (TO-277A)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS compliant

**Terminals:** matte tin plated leads, solderable per J-STD-002

| ABSOLUTE MAXIMUM RATINGS                    |                                   |                          |             |       |
|---------------------------------------------|-----------------------------------|--------------------------|-------------|-------|
| PARAMETER                                   | SYMBOL                            | TEST CONDITIONS          | VALUES      | UNITS |
| Peak repetitive reverse voltage             | V <sub>RRM</sub>                  |                          | 100         | V     |
| Average rectified forward current           | I <sub>F(AV)</sub>                | T <sub>Sp</sub> = 153 °C | 8           | ٨     |
| Non-repetitive peak surge current           | I <sub>FSM</sub>                  | T <sub>J</sub> = 25 °C   | 150         | A     |
| Operating junction and storage temperatures | T <sub>J</sub> , T <sub>Stg</sub> |                          | -55 to +175 | °C    |

| <b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |                  |                                                 |      |      |      |       |
|--------------------------------------------------------------------------------------|------------------|-------------------------------------------------|------|------|------|-------|
| PARAMETER                                                                            | SYMBOL           | TEST CONDITIONS                                 | MIN. | TYP. | MAX. | UNITS |
| Breakdown voltage, blocking voltage                                                  | $V_{BR}, V_{R}$  | I <sub>R</sub> = 100 μA                         | 100  | -    | -    |       |
| Forward voltage                                                                      | V <sub>F</sub>   | I <sub>F</sub> = 8 A                            | -    | 0.91 | 0.98 | V     |
|                                                                                      |                  | I <sub>F</sub> = 8 A, T <sub>J</sub> = 125 °C   | -    | 0.78 | 0.87 |       |
| Reverse leakage current                                                              | I <sub>R</sub> - | $V_{R} = V_{R}$ rated                           | -    | -    | 2    |       |
|                                                                                      |                  | $T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$ | -    | 2    | 15   | μA    |
| Junction capacitance                                                                 | CT               | V <sub>R</sub> = 200 V                          | -    | 43   | -    | pF    |

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1



RoHS

COMPLIANT

HALOGEN



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| <b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25 \text{ °C}$ unless otherwise specified) |                                         |                                                                        |                                                                                  |      |      |      |       |
|---------------------------------------------------------------------------------------------|-----------------------------------------|------------------------------------------------------------------------|----------------------------------------------------------------------------------|------|------|------|-------|
| PARAMETER                                                                                   | SYMBOL                                  | TEST CONDITIONS                                                        |                                                                                  | MIN. | TYP. | MAX. | UNITS |
|                                                                                             |                                         | $I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t =$                          | = 50 A/µs, V <sub>R</sub> = 30 V                                                 | -    | 28   | -    |       |
| Reverse recovery time                                                                       | +                                       | I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A, I <sub>rr</sub> = 0.25 A |                                                                                  | -    | -    | 25   |       |
| Reverse recovery time t <sub>rr</sub>                                                       | ۲r                                      | T <sub>J</sub> = 25 °C                                                 |                                                                                  | -    | 23   | -    | ns    |
|                                                                                             |                                         | T <sub>J</sub> = 125 °C                                                |                                                                                  | -    | 35   | -    |       |
| Deals receivers current                                                                     |                                         | T <sub>J</sub> = 25 °C                                                 | I <sub>F</sub> = 8 A<br>dI <sub>F</sub> /dt = 200 A/μs<br>V <sub>B</sub> = 160 V | -    | 2.5  | -    | A     |
| Peak recovery current                                                                       | IRRM                                    | T <sub>J</sub> = 125 °C                                                |                                                                                  | -    | 5.0  | -    |       |
|                                                                                             | 0                                       | T <sub>J</sub> = 25 °C                                                 |                                                                                  | -    | 28   | -    | nC    |
| Reverse recovery charge                                                                     | leverse recovery charge Q <sub>rr</sub> | T <sub>J</sub> = 125 °C                                                |                                                                                  | -    | 87   | -    |       |

| THERMAL - MECHANICAL SPECIFICATIONS            |                                   |                           |      |      |      |       |
|------------------------------------------------|-----------------------------------|---------------------------|------|------|------|-------|
| PARAMETER                                      | SYMBOL                            | TEST CONDITIONS           | MIN. | TYP. | MAX. | UNITS |
| Maximum junction and storage temperature range | T <sub>J</sub> , T <sub>Stg</sub> |                           | -55  | -    | 175  | °C    |
| Thermal resistance, junction to mount          | R <sub>thJM</sub>                 |                           | -    | 2.2  | 3    | °C/W  |
| Thermal resistance, junction to ambient        | R <sub>thJA</sub>                 |                           | -    | 85   | -    | C/W   |
| Approximate weight                             |                                   |                           |      | 0.1  |      | g     |
| Marking device                                 |                                   | Case style SMPC (TO-277A) | QEH1 |      |      |       |

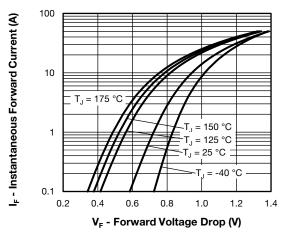


Fig. 1 - Typical Forward Voltage Drop Characteristics

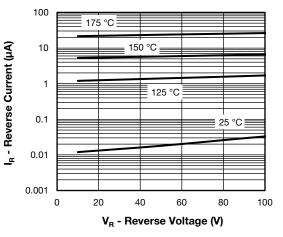
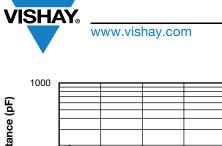


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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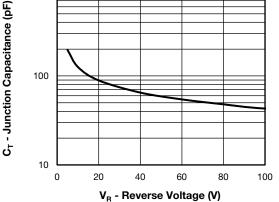
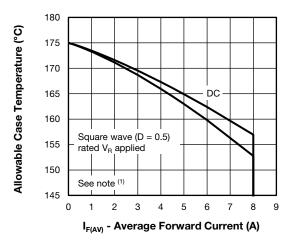
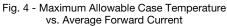
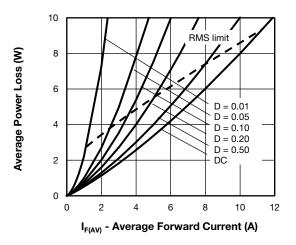
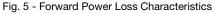


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage









#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

Pd = forward power loss =  $I_{F(AV)} \times V_{FM}$  at ( $I_{F(AV)}/D$ ) (see fig. 5); Pd<sub>REV</sub> = inverse power loss =  $V_{R1} \times I_R$  (1 - D);  $I_R$  at  $V_{R1}$  = rated  $V_R$ 

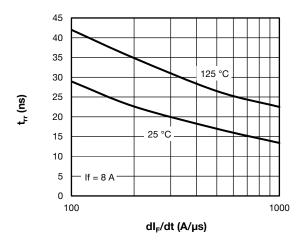


Fig. 6 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

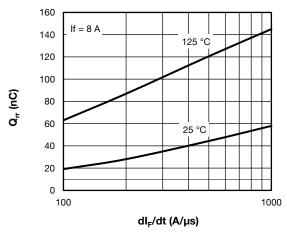


Fig. 7 - Typical Stored Charge vs. dl<sub>F</sub>/dt

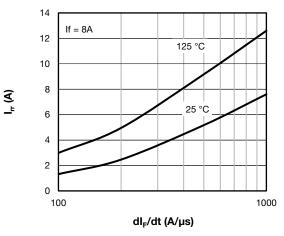


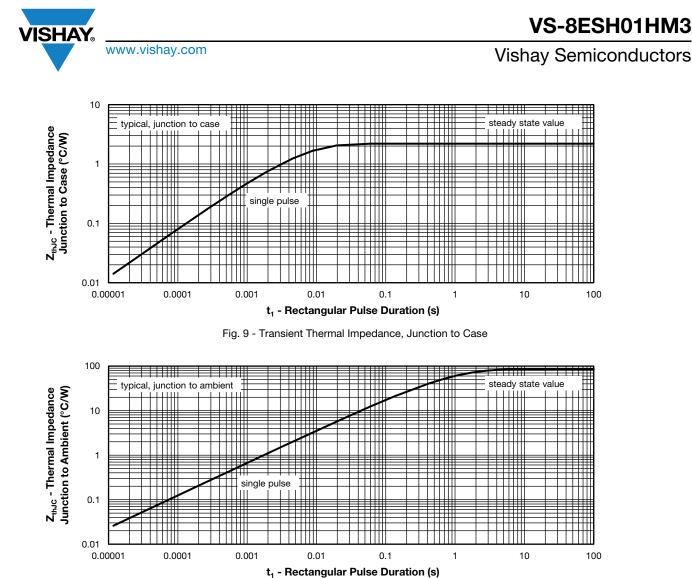
Fig. 8 - Typical Reverse Recovery Current vs. dl<sub>F</sub>/dt

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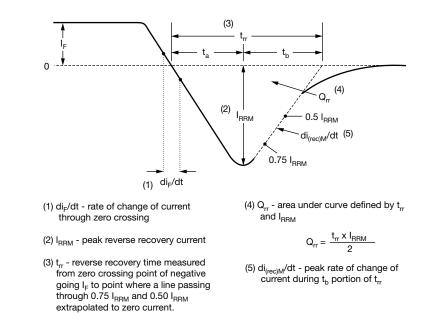
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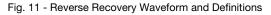
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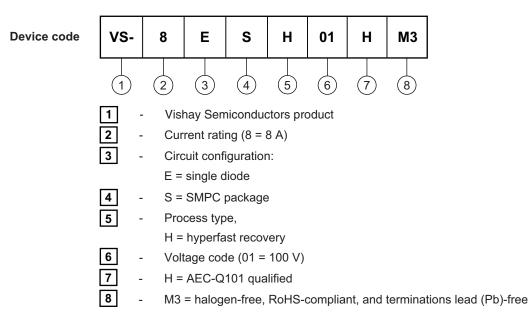




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**ORDERING INFORMATION TABLE** 



| ORDERING INFORMATION (Example) |                                                                             |      |                                    |  |  |  |
|--------------------------------|-----------------------------------------------------------------------------|------|------------------------------------|--|--|--|
| PREFERRED P/N                  | REFERRED P/N QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION |      |                                    |  |  |  |
| VS-8ESH01HM3/H                 | 1500                                                                        | 1500 | 7" diameter plastic tape and reel  |  |  |  |
| VS-8ESH01HM3/I                 | 6500                                                                        | 6500 | 13" diameter plastic tape and reel |  |  |  |

| LINKS TO RELATED DOCUMENTS |                          |  |  |  |
|----------------------------|--------------------------|--|--|--|
| Dimensions                 | www.vishay.com/doc?95570 |  |  |  |
| Part marking information   | www.vishay.com/doc?95565 |  |  |  |
| Packaging information      | www.vishay.com/doc?88869 |  |  |  |
| SPICE model                | www.vishay.com/doc?97016 |  |  |  |



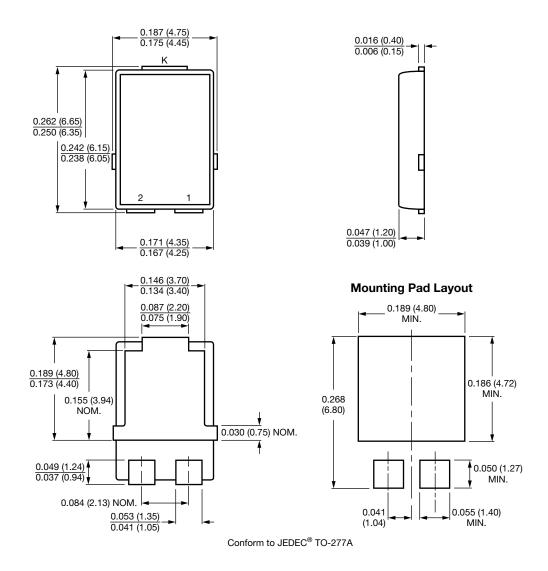
## **Outline Dimensions**





SMPC (TO-277A)

#### **DIMENSIONS** in inches (millimeters)





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1